Low-Cost, General-Purpose High-Speed JFET Amplifier

AD825

FEATURES
High Speed
41 MHz, –3 dB Bandwidth
125 V/μs Slew Rate
80 ns Settling Time
Input Bias Current of 20 pA and Noise Current of
10 fA/$\sqrt{Hz}$
Input Voltage Noise of 12 nV/$\sqrt{Hz}$
Fully Specified Power Supplies: ±5 V to ±15 V
Low Distortion: –76 dB at 1 MHz
High Output Drive Capability
Drives Unlimited Capacitance Load
50 mA Min Output Current
No Phase Reversal When Input Is at Rail
Available in 8-Lead SOIC

APPLICATIONS
CCD
Low Distortion Filters
Mixed Gain Stages
Audio Amplifier
Photo Detector Interface
ADC Input Buffer
DAC Output Buffer
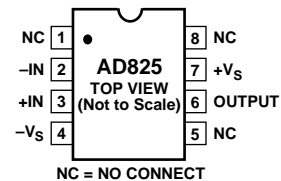
PRODUCT DESCRIPTION

The AD825 is a superbly optimized operational amplifier for high speed, low cost, and dc parameters, making it ideally suited for a broad range of signal conditioning and data acquisition applications. The ac performance, gain, bandwidth, slew rate and drive capability are all very stable over temperature. The AD825 also maintains stable gain under varying load conditions.

The unique input stage has ultralow input bias current and ultralow input current noise. Signals that go to either rail on this high performance input do not cause phase reversals at the output. These features make the AD825 a good choice as a buffer for MUX outputs, creating minimal offset and gain errors.

The AD825 is fully specified for operation with dual ±5 V and ±15 V supplies. This power supply flexibility, and the low supply current of 6.5 mA with excellent ac characteristics under all supply conditions, make the AD825 well suited for many demanding applications.

CONNECTION DIAGRAMS

8-Lead Plastic SOIC (R) Package

	AD825 TOP VIEW (Not to Scale)	
NC [1]		[8] NC
–IN [2]		[7] +V$_S$
+IN [3]		[6] OUTPUT
–V$_S$ [4]		[5] NC

NC = NO CONNECT

16-Lead Plastic SOIC (R-16) Package

	AD825 TOP VIEW (Not to Scale)	
NC [1]		[16] NC
NC [2]		[15] NC
NC [3]		[14] NC
–INPUT [4]		[13] +V$_S$
+INPUT [5]		[12] OUTPUT
–V$_S$ [6]		[11] NC
NC [7]		[10] NC
NC [8]		[9] NC

NC = NO CONNECT
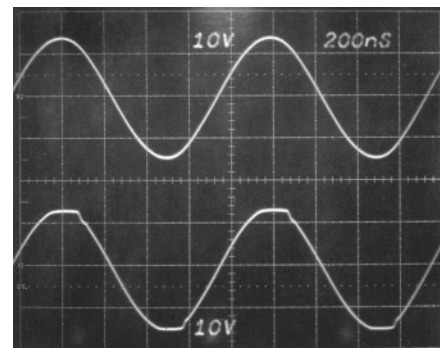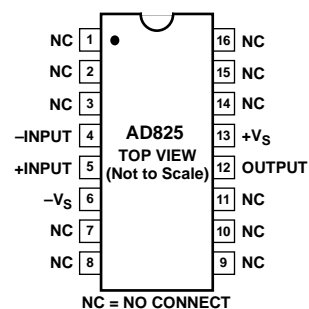
Figure 1. Performance with Rail-to-Rail Input Signals

AD825–SPECIFICATIONS (@ T_A = 25°C, V_S = ±15 V unless otherwise noted)

Parameter	Conditions	V_S	AD825A Min	AD825A Typ	AD825A Max	Unit
DYNAMIC PERFORMANCE						
Unity Gain Bandwidth		±15 V	23	26		MHz
Bandwidth for 0.1 dB Flatness	Gain = +1	±15 V	18	21		MHz
–3 dB Bandwidth	Gain = +1	±15 V	44	46		MHz
Slew Rate	R_{LOAD} = 1 kΩ, G = 1	±15 V	125	140		V/μs
Settling Time to 0.1%	0 V–10 V Step, A_V = –1	±15 V		150	180	ns
to 0.01%	0 V–10 V Step, A_V = –1	±15 V		180	220	ns
Total Harmonic Distortion	F_C = 1 MHz, G = –1	±15 V		–77		dB
Differential Gain Error	NTSC	±15 V		1.3		%
(R_{LOAD} = 150 Ω)	Gain = +2					
Differential Phase Error	NTSC	±15 V		2.1		Degrees
(R_{LOAD} = 150 Ω)	Gain = +2					
INPUT OFFSET VOLTAGE		±15 V		1	2	mV
	T_{MIN} to T_{MAX}				5	mV
Offset Drift				10		μV/°C
INPUT BIAS CURRENT		±15 V		15	40	pA
	T_{MIN}		5			pA
	T_{MAX}				700	pA
INPUT OFFSET CURRENT		±15 V		20	30	pA
	T_{MIN}		5			pA
	T_{MAX}				440	pA
OPEN LOOP GAIN	V_{OUT} = ±10 V	±15 V				
	R_{LOAD} = 1 kΩ		70	76		dB
	V_{OUT} = ±7.5 V	±15 V				
	R_{LOAD} = 1 kΩ		70	76		dB
	V_{OUT} = ±7.5 V	±15 V				
	R_{LOAD} = 150 Ω		72	74		dB
	(50 mA Output)					
COMMON-MODE REJECTION	V_{CM} = ±10 V	±15 V	71	80		dB
INPUT VOLTAGE NOISE	f = 10 kHz	±15 V		12		nV/√Hz
INPUT CURRENT NOISE	f = 10 kHz	±15 V		10		fA/√Hz
INPUT COMMON-MODE VOLTAGE RANGE		±15 V		±13.5		V
OUTPUT VOLTAGE SWING	R_{LOAD} = 1 kΩ	±15 V	13	±13.3		V
	R_{LOAD} = 500 Ω	±15 V	12.9	±13.2		V
Output Current		±15 V	50			mA
Short-Circuit Current		±15 V		100		mA
INPUT RESISTANCE				5×10^{11}		Ω
INPUT CAPACITANCE				6		pF
OUTPUT RESISTANCE	Open Loop			8		Ω
POWER SUPPLY						
Quiescent Current		±15 V		6.5	7.2	mA
	T_{MIN} to T_{MAX}	±15 V			7.5	mA

NOTES
All limits are determined to be at least four standard deviations away from mean value.
Specifications subject to change without notice.

REV. D

SPECIFICATIONS (@ T_A = 25°C, V_S = ±5 V unless otherwise noted)

Parameter	Conditions	V_S	AD825A Min	AD825A Typ	AD825A Max	Unit
DYNAMIC PERFORMANCE						
Unity Gain Bandwidth		±5 V	18	21		MHz
Bandwidth for 0.1 dB Flatness	Gain = +1	±5 V	8	10		MHz
−3 dB Bandwidth	Gain = +1	±5 V	34	37		MHz
Slew Rate	R_{LOAD} = 1 kΩ, G = −1	±5 V	115	130		V/µs
Settling Time to 0.1%	−2.5 V to +2.5 V	±5 V		75	90	ns
to 0.01%	−2.5 V to +2.5 V	±5 V		90	110	ns
Total Harmonic Distortion	F_C = 1 MHz, G = −1	±5 V		−76		dB
Differential Gain Error	NTSC	±5 V		1.2		%
(R_{LOAD} = 150 Ω)	Gain = +2					
Differential Phase Error	NTSC	±5 V		1.4		Degrees
(R_{LOAD} = 150 Ω)	Gain = +2					
INPUT OFFSET VOLTAGE		±5 V		1	2	mV
	T_{MIN} to T_{MAX}				5	mV
Offset Drift				10		µV/°C
INPUT BIAS CURRENT		±5 V		10	30	pA
	T_{MIN}		5			pA
	T_{MAX}				600	pA
INPUT OFFSET CURRENT		±5 V		15	25	pA
	T_{MIN}		5			pA
Offset Current Drift	T_{MAX}				280	pA
OPEN LOOP GAIN	V_{OUT} = ±2.5 V	±5 V				
	R_{LOAD} = 500 Ω		64	66		dB
	R_{LOAD} = 150 Ω		64	66		dB
COMMON-MODE REJECTION	V_{CM} = ±2 V	±5 V	69	80		dB
INPUT VOLTAGE NOISE	f = 10 kHz	±5 V		12		nV/√Hz
INPUT CURRENT NOISE	f = 10 kHz	±5 V		10		fA/√Hz
INPUT COMMON-MODE VOLTAGE RANGE		±5 V		±3.5		V
OUTPUT VOLTAGE SWING	R_{LOAD} = 500 Ω		3.2	±3.4		V
	R_{LOAD} = 150 Ω	±5 V	3.1	±3.2		V
Output Current		±5 V	50			mA
Short-Circuit Current		±5 V		80		mA
INPUT RESISTANCE				5×10^{11}		Ω
INPUT CAPACITANCE				6		pF
OUTPUT RESISTANCE	Open Loop			8		Ω
POWER SUPPLY						
Quiescent Current		±5 V		6.2	6.8	mA
	T_{MIN} to T_{MAX}	±5 V			7.5	mA
POWER SUPPLY REJECTION	V_S = ±5 V to ±15 V		76	88		dB

NOTES
All limits are determined to be at least four standard deviations away from mean value.

Specifications subject to change without notice.

AD825

ABSOLUTE MAXIMUM RATINGS[1]

Supply Voltage . . . . ± 18 V
Internal Power Dissipation[2]
   Small Outline (R) . . . . See Derating Curves
Input Voltage (Common Mode) . . . . $\pm V_S$
Differential Input Voltage . . . . $\pm V_S$
Output Short Circuit Duration . . . . See Derating Curves
Storage Temperature Range (R, R-16) . . . . –65°C to +125°C
Operating Temperature Range . . . . –40°C to +85°C
Lead Temperature Range (Soldering 10 sec) . . . . 300°C

NOTES
[1]Stresses above those listed under Absolute Maximum Ratings may cause perma-
  nent damage to the device. This is a stress rating only; functional operation of the
  device at these or any other conditions above those indicated in the operational
  section of this specification is not implied. Exposure to absolute maximum rating
  conditions for extended periods may affect device reliability.
[2]Specification is for device in free air:
  8-lead SOIC package: θ_{JA} = 155°C/W
  16-lead SOIC package: θ_{JA} = 85°C/W

PIN CONFIGURATION

```
        ┌──────∪──────┐
 NC  1 │●            8 │ NC
−IN  2 │    AD825     7 │ +V_S
+IN  3 │  TOP VIEW    6 │ OUTPUT
       │ (Not to Scale)
−V_S 4 │            5 │ NC
        └─────────────┘
       NC = NO CONNECT
```
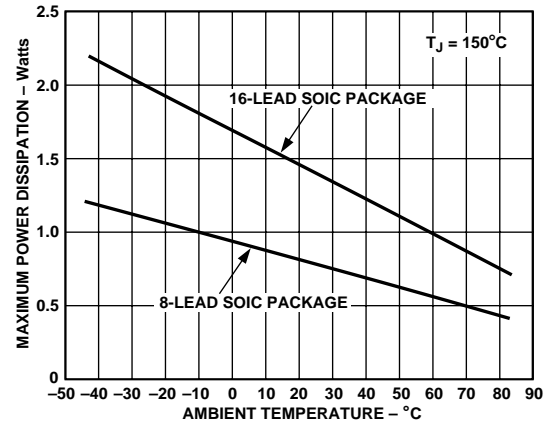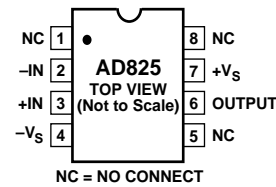

Figure 2. Maximum Power Dissipation vs. Temperature

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD825AR	–40°C to +85°C	8-Lead Plastic SOIC	SO-8
AD825ACHIPS	–40°C to +85°C	Die	
AD825AR-REEL	–40°C to +85°C	13" Tape and Reel	SO-8
AD825AR-REEL7	–40°C to +85°C	7" Tape and Reel	SO-8
AD825AR-16	–40°C to +85°C	16-Lead Plastic SOIC	R-16
AD825AR-16-REEL	–40°C to +85°C	13" Tape and Reel	R-16
AD825AR-16-REEL7	–40°C to +85°C	7" Tape and Reel	R-16

REV. D
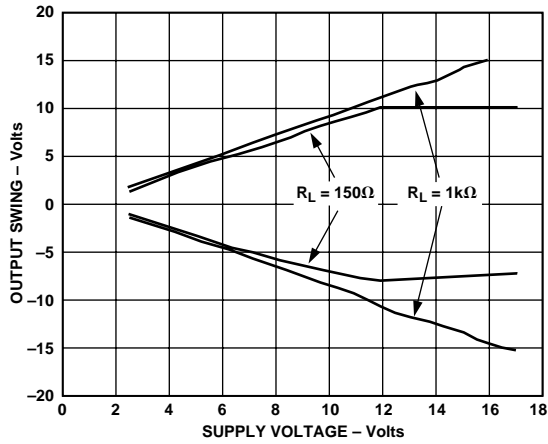
TPC 1. Output Voltage Swing vs. Supply

TPC 2. Output Voltage Swing vs. Load Resistance

TPC 3. Quiescent Supply Current vs. Supply Voltage for Various Temperatures

TPC 4. Closed-Loop Output Impedance vs. Frequency

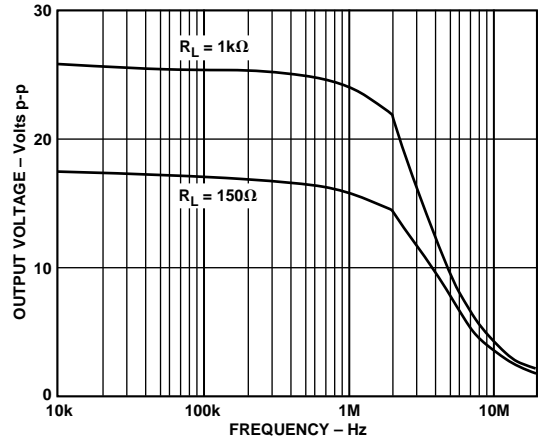TPC 5. Unity Gain Bandwidth and Phase Margin vs. Temperature
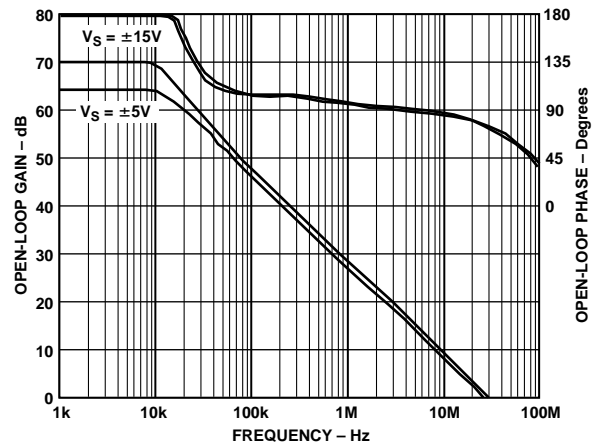
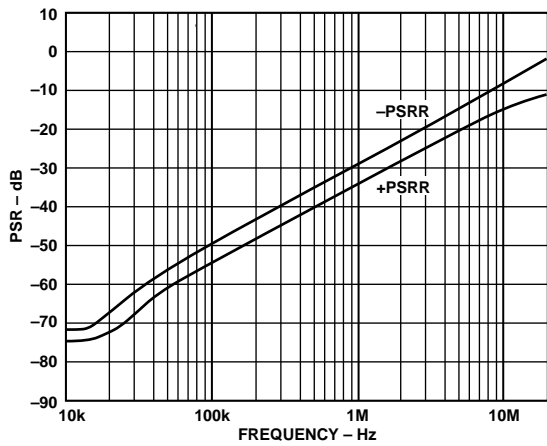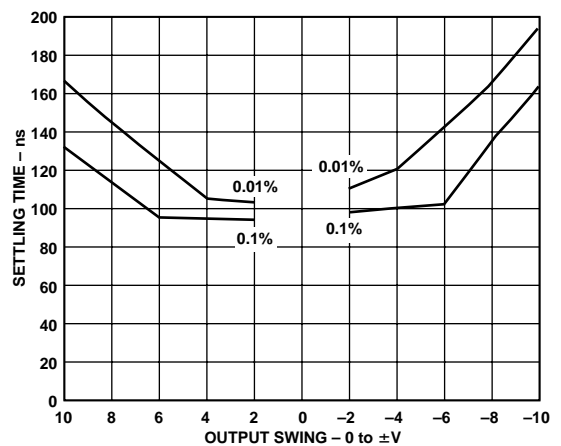TPC 6. Open-Loop Gain and Phase Margin vs. Frequency

AD825
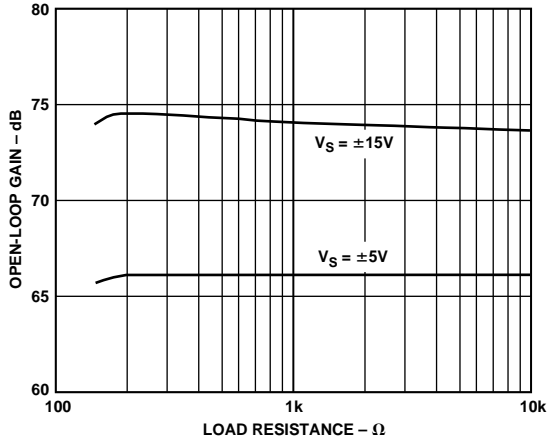
TPC 7. Open-Loop Gain vs. Load Resistance

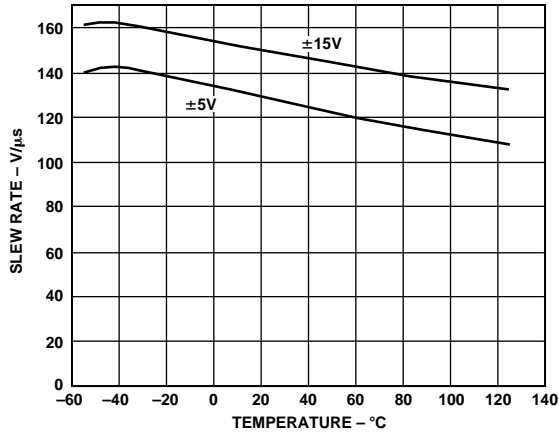TPC 10. Large Signal Frequency Response; G = +2

TPC 8. Power Supply Rejection vs. Frequency

TPC 11. Output Swing and Error vs. Settling Time
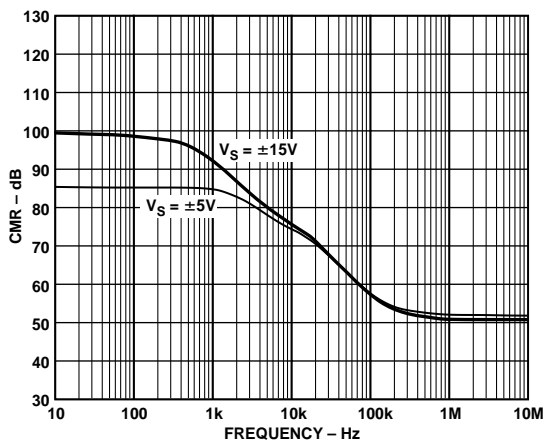
TPC 9. Common-Mode Rejection vs. Frequency
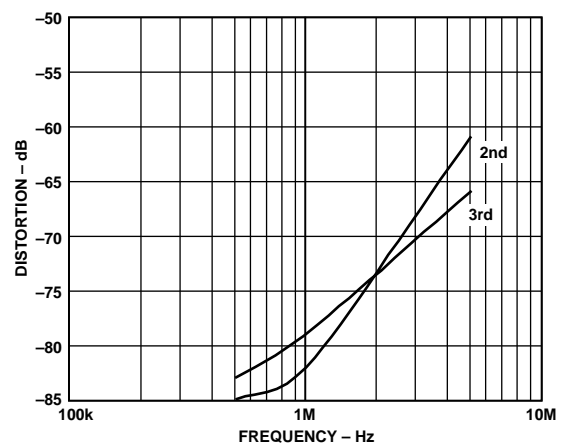
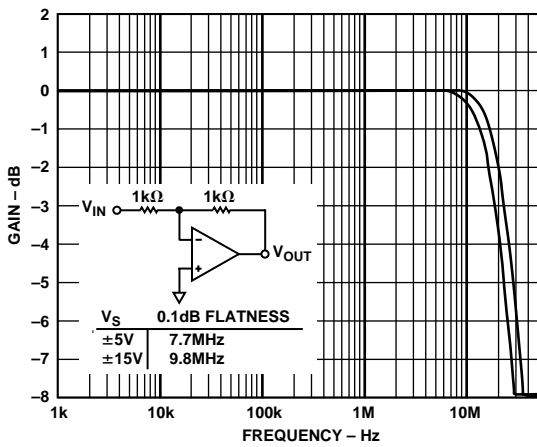TPC 12. Harmonic Distortion vs. Frequency

TPC 13. Slew Rate vs. Temperature
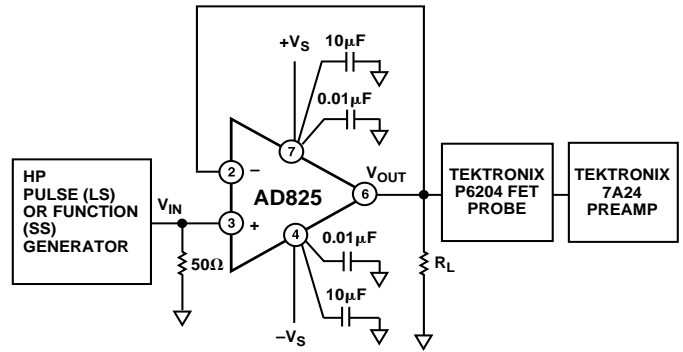
TPC 16. Noninverting Amplifier Connection
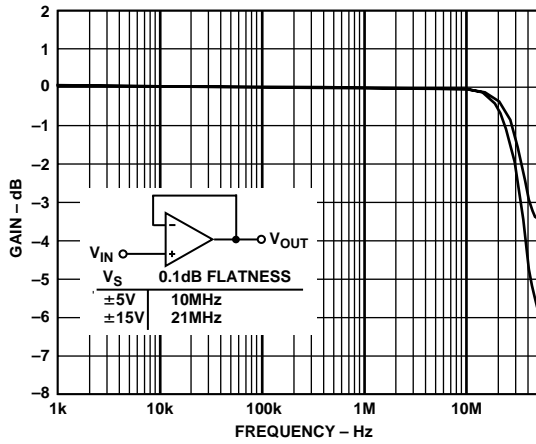
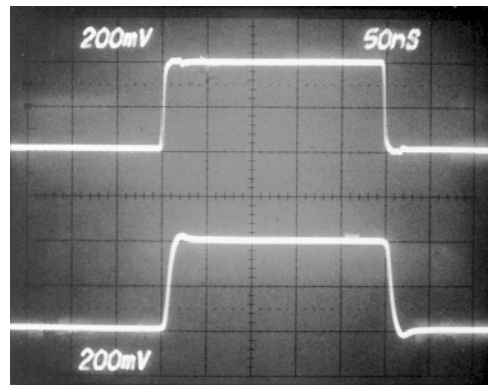TPC 14. Closed-Loop Gain vs. Frequency, Gain = +1
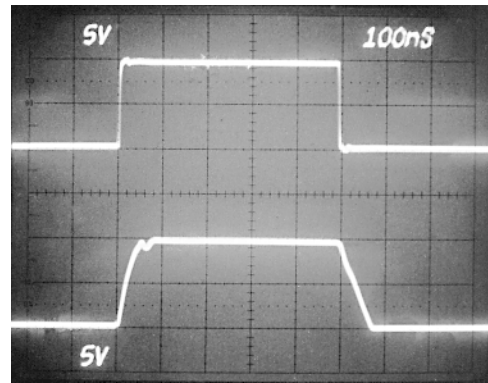
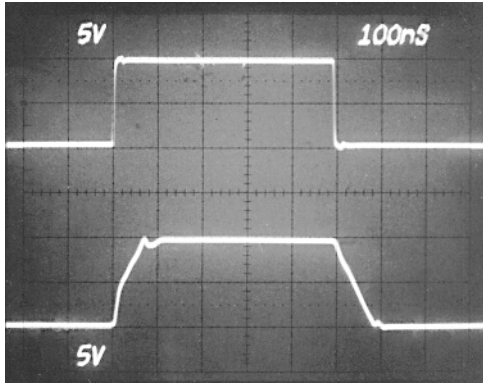TPC 17. Noninverting Large Signal Pulse Response, $R_L = 1 k\Omega$
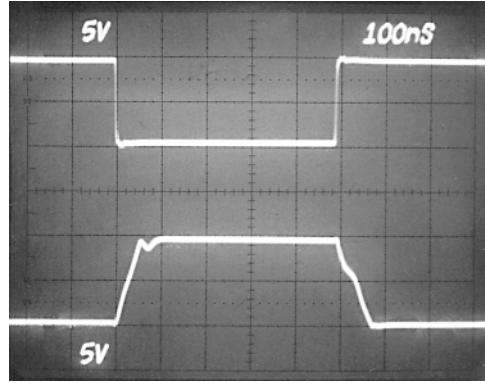

TPC 15. Closed-Loop Gain vs. Frequency, Gain = –1

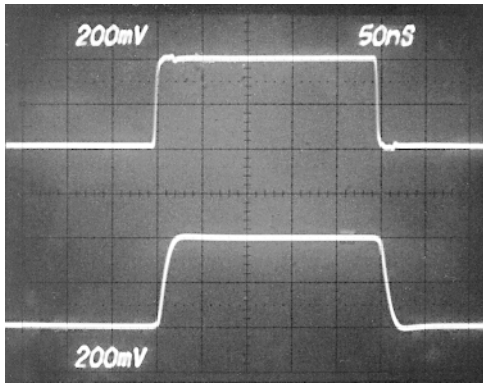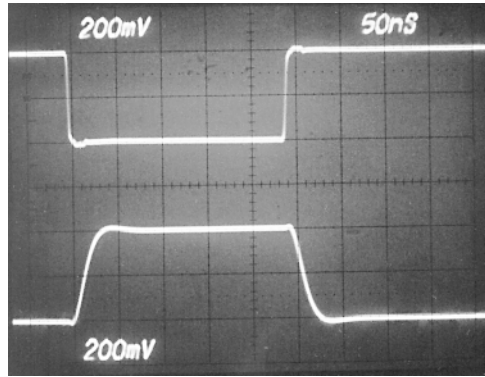TPC 18. Noninverting Small Signal Pulse Response, $R_L = 1 k\Omega$

AD825

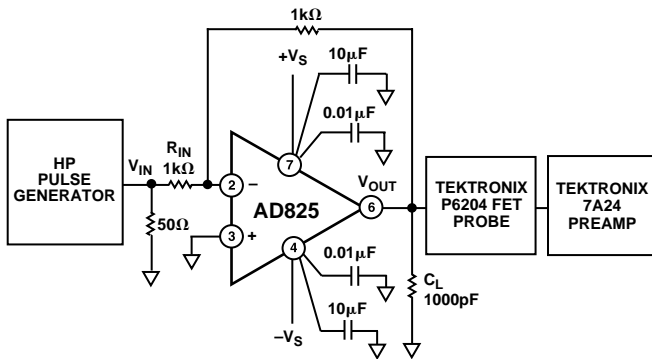TPC 19. Noninverting Large Signal Pulse Response, $R_L = 150 \, \Omega$

TPC 22 . Inverting Large Signal Pulse Response, $R_L = 1 \, k\Omega$

TPC 20. Noninverting Small Signal Pulse Response, $R_L = 150 \, \Omega$

TPC 23. Inverting Small Signal Pulse Response, $R_L = 1 \, k\Omega$

TPC 21. Inverting Amplifier Connection

REV. D

DRIVING CAPACITIVE LOADS

The internal compensation of the AD825, together with its high output current drive, permits excellent large signal performance while driving extremely high capacitive loads.
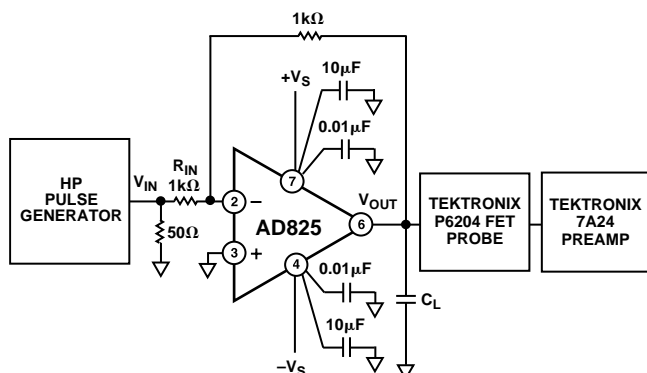

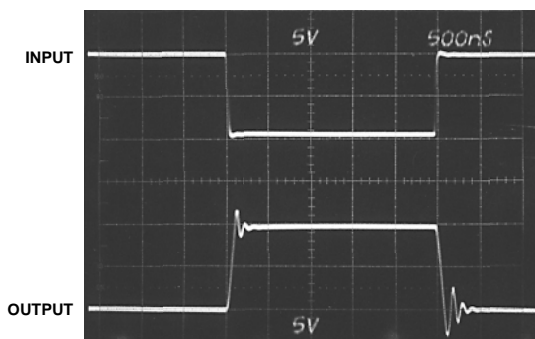Figure 3a. Inverting Amplifier Driving a Capacitive Load

Figure 3b. Inverting Amplifier Pulse Response While Driving a 400 pF Capacitive Load

THEORY OF OPERATION

The AD825 is a low cost, wide band, high performance FET input operational amplifier. With its unique input stage design, the AD825 assures no phase reversal even for inputs that exceed the power supply voltages, and its output stage is designed to drive heavy capacitive or resistive load with small changes relative to no load condition.

The AD825 (Figure 4) consists of common-drain common-base FET input stage driving a cascoded, common base matched NPN gain stage. The output buffer stage uses emitter followers in a class AB amplifier that can deliver large current to the load while maintaining low levels of distortion.
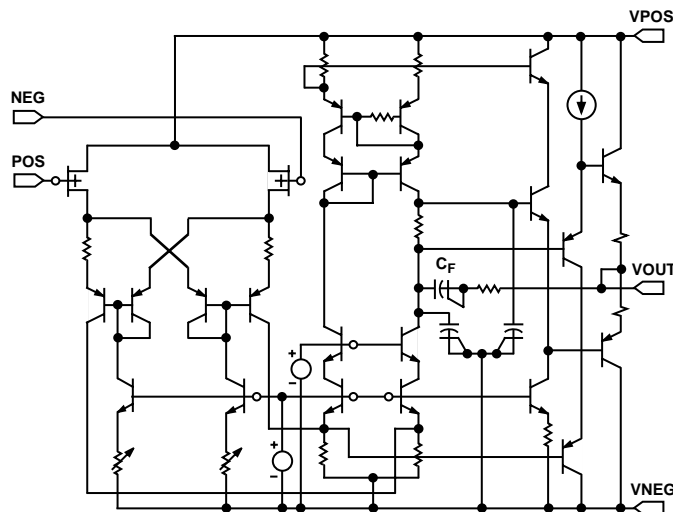

Figure 4. Simplified Schematic

The capacitor, C_F, in the output stage, enables the AD825 to drive heavy capacitive load. For light load, the gain of the output buffer is close to unity, C_F is bootstrapped and not much happens. As the capacitive load is increased, the gain of the output buffer is decreased and the bandwidth of the amplifier is reduced through a portion of C_F adding to the dominant pole. As the capacitive load is further increased, the amplifier's bandwidth continues to drop, maintaining the stability of the AD825.

Input Consideration

The AD825 with its unique input stage assures no phase reversal for signals as large or even larger than the supply voltages. Also, layout considerations of the input transistors assure functionality even with a large differential signal.

The need for a low noise input stage calls for a larger FET transistor. One should consider the additional capacitance that is added to assure stability. When filters are designed with the AD825, one needs to consider the input capacitance (5 pF–6 pF) of the AD825 as part of the passive network.

Grounding and Bypassing

The AD825 is a low input bias current FET amplifier. Its high frequency response makes it useful in applications such as photo diode interfaces, filters and audio circuits. When designing high frequency circuits, some special precautions are in order. Circuits must be built with short interconnects, and resistances should have low inductive paths to ground. Power supply leads should be bypassed to common as close as possible to the amplifier pins. Ceramic capacitors of 0.1 μF are recommended.

AD825

Second Order Low-Pass Filter

A second order Butterworth low-pass filter can be implemented using the AD825 as shown in Figure 5. The extremely low bias currents of the AD825 allow the use of large resistor values, and consequently small capacitor values, without concern for developing large offset errors. Low current noise is another factor in permitting the use of large resistors without having to worry about the resultant voltage noise.

With the values shown, the corner frequency will be 1 MHz. The equations for component selection are shown below. Note that the noninverting input (and the inverting input) has an input capacitance of 6 pF. As a result, the calculated value of C1 (12 pF) is reduced to 6 pF.

$$C1 = \frac{1.414}{2\pi\, f_{CUTOFF} R1}$$

$$C2\,(farads) = \frac{0.707}{2\pi\, f_{CUTOFF} R1}$$

$$R1 = R2 = user\ selected\ \left(typically\ 10\,k\Omega\ to\ 100\,k\Omega\right)$$

A plot of the filter frequency response is shown in Figure 6; better than 40 dB of high frequency rejection is provided.
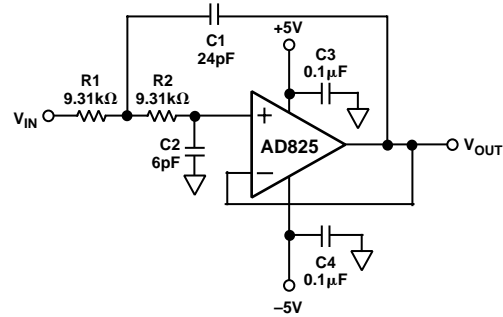
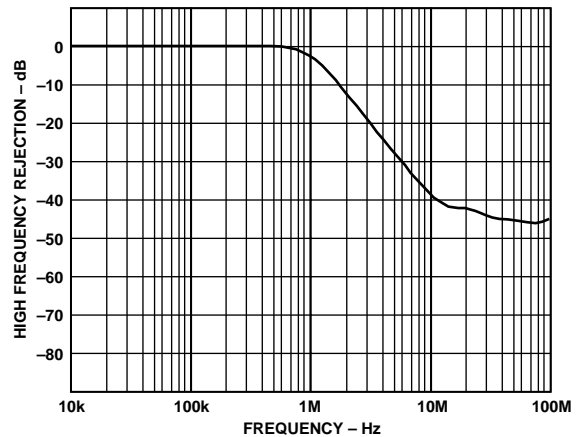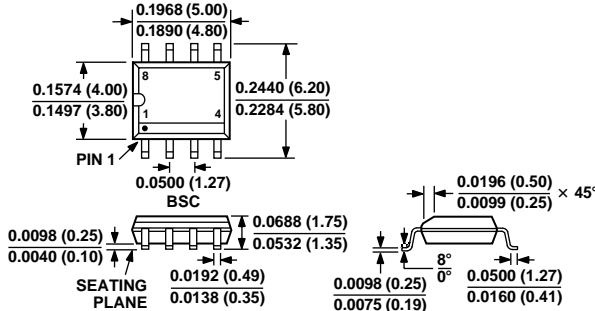

Figure 5. Second Order Butterworth Low-Pass Filter

Figure 6. Frequency Response of Second Order Butterworth Filter
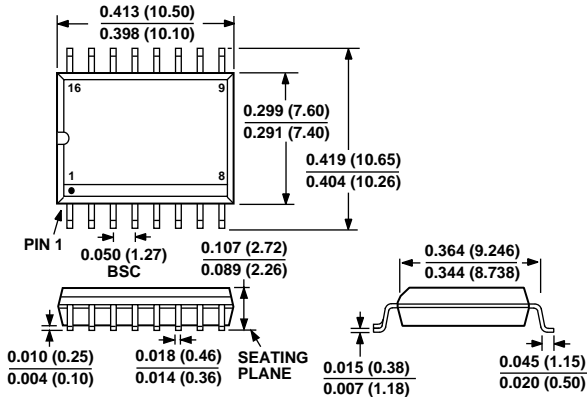
OUTLINE DIMENSIONS
Dimensions shown in inches and (mm).

8-Lead Plastic SOIC
(SO-8)

16-Lead Plastic SOIC
(R-16)

AD825–Revision History

REV. D